

Features:

- DC 3.0 GHz
- 30 Watts
- BeO Ceramic
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

Chip Termination 30 Watts, 50Ω

General Specifications

Resistive Element Thick film

Substrate Beryllium oxide ceramic

Terminals Thick film silver

Electrical Specifications

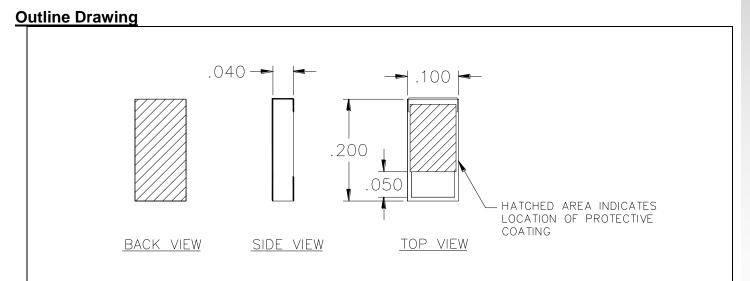
Resistance Range: 50 ohms, \pm 2% Frequency Range; DC - 3.0 GHz Power: 30 Watts

VSWR 1.25:1 DC – 3.0 GHz

Note: Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet of exceed applicable portions of MIL-E-5400. Operating temperature is -55°C to 150°C (see chart for derating temperatures).

All dimensions in inches.

Specifications subject to change with out notice.



100200-4X50-2 (097) Rev B





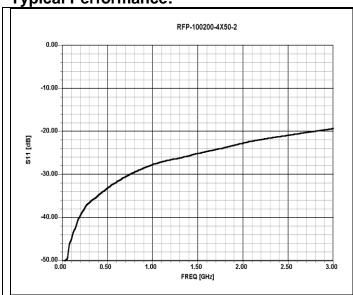
Available on Tape and Reel For Pick and Place Manufacturing.

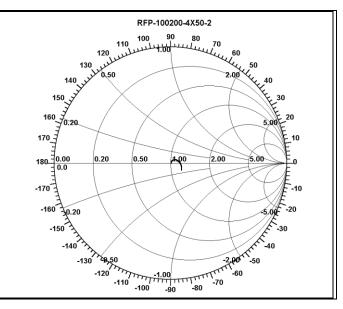
USA/Canada: (315) 432-8909 Toll Free: (800) 544-2414 Europe: +44 2392-232392





Typical Performance:

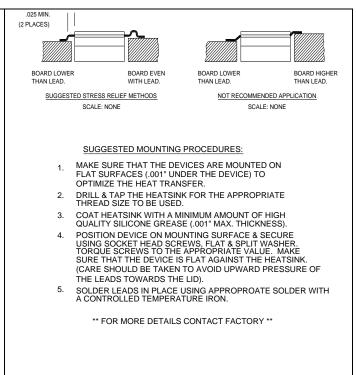




Power De-rating:

POWER DERATING RATED POWER 100 75 50 25 OF No. 0 75 25 50 100 125 150 P.C.B. SOLDER INTERFACE TEMPERATURE-C

Mounting Footprint and Procedure:



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